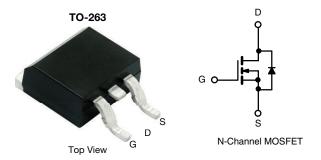


www.vishay.com

Vishay Siliconix

Automotive N-Channel 150 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	150				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.052				
I _D (A)	25				
Configuration	Single				
Package	TO-263				



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS	$(T_C = 25 ^{\circ}C, unles)$	s otherwise noted	(k	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V_{DS}	150	V	
Gate-Source Voltage	Gate-Source Voltage			V
Continuous Drain Current	T _C = 25 °C	1	25	
Continuous Drain Current	T _C = 125 °C	ID	16	
Continuous Source Current (Diode Conduction) ^a	I _S	50	Α
Pulsed Drain Current ^b	I _{DM}	65		
Single Pulse Avalanche Energy L = 0.1 mH		I _{AS}	30	
Single Pulse Avalanche Current		E _{AS}	45	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	Pn	107	W
Maximum Fower Dissipation -	T _C = 125 °C	r-D	35	VV
Operating Junction and Storage Temperature I	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount c	R_{thJA}	40	°C ///		
Junction-to-Case (Drain)		R_{thJC}	1.4	°C/W		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static	1	1			L			
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} :	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	2.5	3	4	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 150 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 150 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 150 V, T _J = 175 °C	-	-	250	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	Α	
		V _{GS} = 10 V	I _D = 15 A	-	0.041	0.052	Ω	
Drain-Source On-State Resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 125 °C	-	-	0.106		
		V _{GS} = 10 V	I _D = 15 A, T _J = 175 °C	-	-	0.138	1	
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 15 A		-	33	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	1886	2360		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	215	270	pF	
Reverse Transfer Capacitance	C _{rss}			-	97	125		
Total Gate Charge ^c	Qg			-	34	51		
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 75 \text{ V}, I_{D} = 25 \text{ A}$	-	14.5	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	5.4	=		
Gate Resistance	R_g		f = 1 MHz		1.0	3.2	Ω	
Turn-On Delay Time ^c	t _{d(on)}				11	17		
Rise Time ^c	t _r	$V_{DD} = 75 \text{ V}, R_L = 3 \Omega$ $I_D \cong 25 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		-	21	33		
Turn-Off Delay Time ^c	t _{d(off)}			-	20	30	ns	
Fall Time ^c	t _f			-	12	20		
Source-Drain Diode Ratings and Chara	cteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	65	Α	
Forward Voltage	V_{SD}	I _F = 20 A, V _{GS} = 0 V		_	0.85	1.5	V	

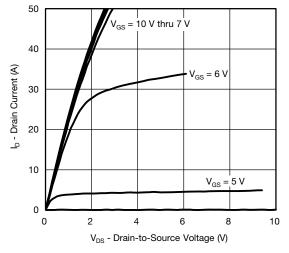
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

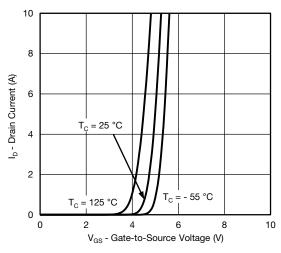
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



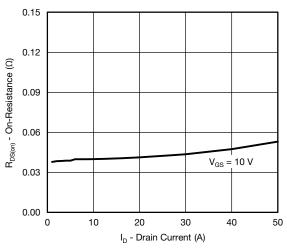
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



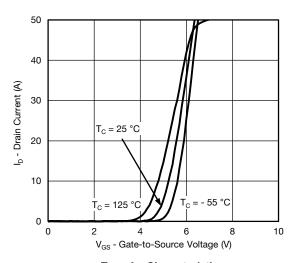
Output Characteristics



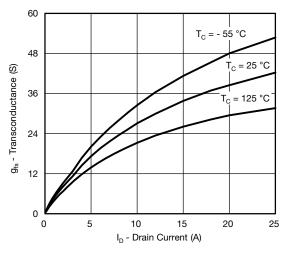
Transfer Characteristics



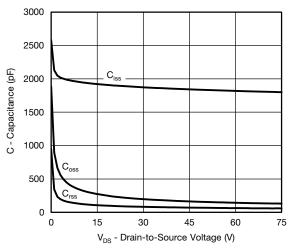
On-Resistance vs. Drain Current



Transfer Characteristics



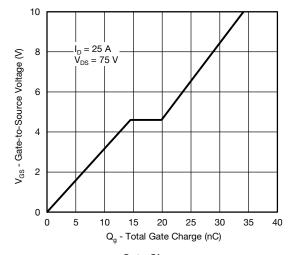
Transconductance



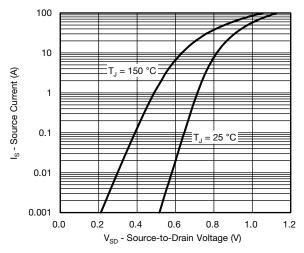
Capacitance



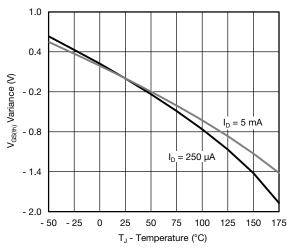
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



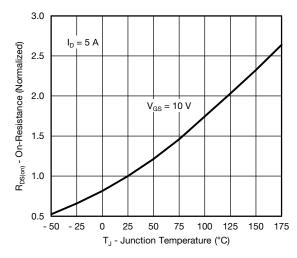
Gate Charge



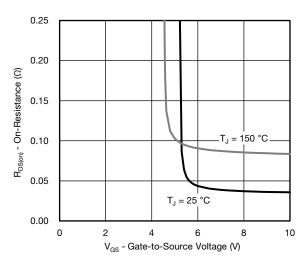
Source Drain Diode Forward Voltage



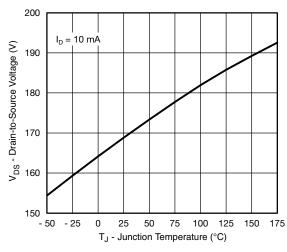
Threshold Voltage



On-Resistance vs. Junction Temperature



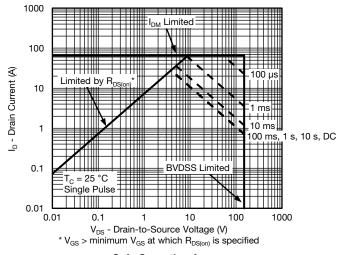
On-Resistance vs. Gate-to-Source Voltage



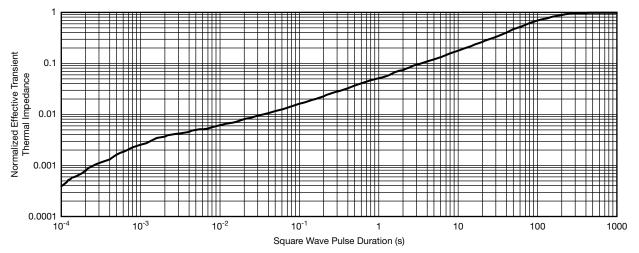
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



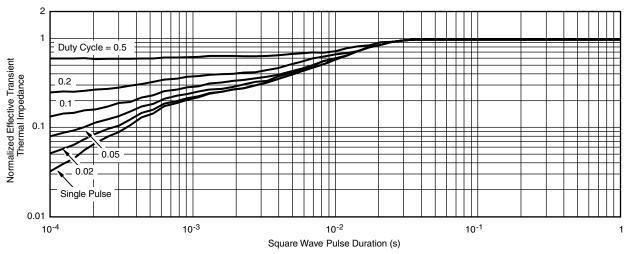
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

can widely vary depending on actual application parameters and operating conditions.

- Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities

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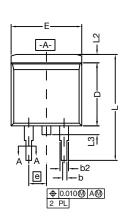
REVISION HISTORY ^a					
REVISION	DATE	DESCRIPTION OF CHANGE			
D	08-Aug-15	R _g , C _{rss} , t _r and t _f changed			

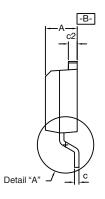
Note

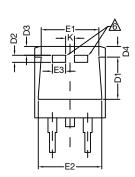
a. As of April 2014



TO-263 (D²PAK): 3-LEAD

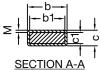








DETAIL A (ROTATED 90°)



⋝:	b b1	ţ
2:	T /////// 5	
	SECTION A.	Ţ

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

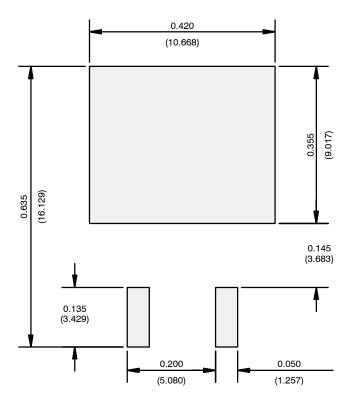
		INC	HES	MILLIMETERS		
	DIM.	MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100) BSC	2.54 BSC		
K		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
	L3	0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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